NSN 5961-00-181-0525

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-181-0525 **Inclosure Material:** Glass and metal **Overall Length:** 2.500 inches **Overall Diameter:** 1.031 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-30 **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 1.156 inches **Thread Size:** 0.500 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 reverse voltage, peak **Current Rating Per Characteristic:** 3000.00 milliamperes average forward current averaged over a full 60-hz cycle **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius case **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud **Specification Data:** 80131-release2820 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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